


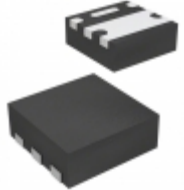

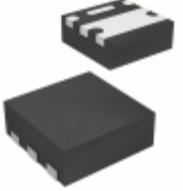



	<h2>SIA450DJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA450DJ-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 240V 1.52A SC70-6</p> <p>Datenblätter:  SIA450DJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 29933 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA450DJ-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 240V 1.52A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	29933 pcs Stock
detaillierte Beschreibung	N-Channel 240V 1.52A (Tc) 3.3W (Ta), 15W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SC-70-6
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Single
Verlustleistung (max)	3.3W (Ta), 15W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	240V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.52A (Tc)
Rds On (Max) @ Id, Vgs	2.9 Ohm @ 700mA, 10V
VGS (th) (Max) @ Id	2.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.04nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	167pF @ 120V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

SIA450DJ-T1-GE3 ist neu im Original, Suche SIA450DJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA450DJ-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIA450DJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA4528-100K DELTA SIA4528-100K DELTA</p>	 <p>SIA453EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 24A PPAK SC-70-6</p>	 <p>SIA449DJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 12A SC70-6</p>	 <p>SIA450DJ-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 240V 1.52A SC70-6</p>
 <p>SIA450DJ-T1-E3 Vishay / Siliconix MOSFET N-CH 240V 1.52A SC70-6</p>	 <p>SIA449DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 12A SC70-6</p>	 <p>SIA450DJ-T1-GE3 Vishay / Siliconix MOSFET N-CH 240V 1.52A SC70-6</p>	 <p>SIA453EDJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 24A PPAK SC-70-6</p>

heiße Teile

Mehr

SIA429DJT-T1-GE3	SIA430DJ-T1-GE3	SIA430DJ-T1-GE3	SIA431DJ	SIA431DJ-T1
SIA431DJ-T1-GE3	SIA431DJ-T1-GE3	SIA432DJ-T1-GE3	SIA432DJ-T1-GE3	SIA433EDJ
SIA433EDJ-T1-GE3	SIA433EDJ-T1-GE3	SIA436DJ-T1-GE3	SIA436DJ-T1-GE3	SIA443DJ-T1-GE3
SIA443DJ-T1-GE3	SIA444DJT-T1-GE3	SIA444DJT-T1-GE3	SIA445EDJ-T1-GE3	SIA445EDJ-T1-GE3
SIA447DJ-T1-GE3	SIA447DJ-T1-GE3	SIA448DJ-T1-GE3	SIA448DJ-T1-GE3	SIA449DJ-GE3
SIA450DJ-T1-GE3	SIA4528-100K	SIA4528-330K	SIA4528-470K	SIA453EDJ-T1-GE3
SIA453EDJ-T1-GE3	SIA456DJ-T1-GE3	SIA456DJ-T1-GE3	SIA483DJ-T1-GE3	SIA483DJ-T1-GE3
SIA513DJ-T1-E3	SIA517DJ-T1-GE3	SIA517DJ-T1-GE3	SIA517DJ-T4-GE3	SIA519EDJ-T1-GE3
SIA519EDJ-T1-GE3	SIA533EDJ-T1-GE3	SIA533EDJ-T1-GE3	SIA778DJ-T1-GE3	SIA778DJ-T1-GE3
SIA811ADJ-T1-GE3	SIA811ADJ-T1-GE3	SIA811DJ-T1	SIA811DJ-T1-E3	SIA811DJ-T1-E3

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